

采用 6 引脚 SOT-23 封装的 TPS56x209 4.5V 至 17V 输入、2A、3A 同步降压稳压器

1 特性

- TPS562209 - 集成有 122mΩ 和 72mΩ FET 的 2A 转换器
- TPS563209 - 带有集成 68mΩ 和 39mΩ FET 的 3A 转换器
- D-CAP2™ 针对快速瞬态响应的模式控制
- 输入电压范围: 4.5V 至 17V
- 输出电压范围: 0.76V 至 7V
- 650kHz 开关频率
- 低于 10μA 的低关断电流
- 1% 反馈电压精度 (25°C)
- 从预偏置输出电压中启动
- 逐周期过流限制
- 断续模式欠压保护
- 非锁存过压保护 (OVP), 欠压闭锁 (UVLO) 和热关断 (TSD) 保护
- 固定软启动时间: 1.0ms

2 应用

- 数字电视电源
- 高清 Blu-ray Disc™ 播放器
- 网络家庭终端设备
- 数字机顶盒 (STB)

3 说明

TPS562209 和 TPS563209 是采用 6 引脚 SOT-23 封装的简单易用型 2A/3A 同步降压转换器。

此器件被优化为使用尽可能少的外部组件即可运行，并且可以实现低待机电流。

这些开关模式电源 (SMPS) 器件采用 D-CAP2™ 模式控制，从而提供快速瞬态响应，并且在无需外部补偿组件的情况下支持诸如高分子聚合物等低等效串联电阻 (ESR) 输出电容器以及超低 ESR 陶瓷电容器。

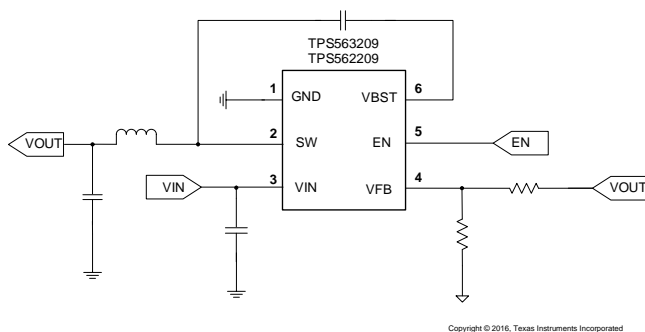
TPS562209 和 TPS563209 始终在连续传导模式下运行，与非连续传导模式相比，该模式可降低轻负载条件下的输出纹波电压。TPS56x209 采用 6 引脚 1.6mm x 2.9mm SOT (DDC) 封装，结温范围为 -40°C 至 150°C。

器件信息(1)

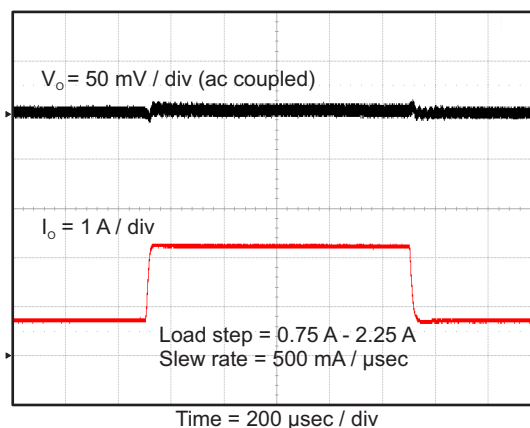
器件型号	封装	封装尺寸 (标称值)
TPS563209, TPS562209	SOT (6)	1.60mm x 2.90mm

(1) 如需了解所有可用封装，请见数据表末尾的可订购产品附录。

简化电路原理图



瞬态响应



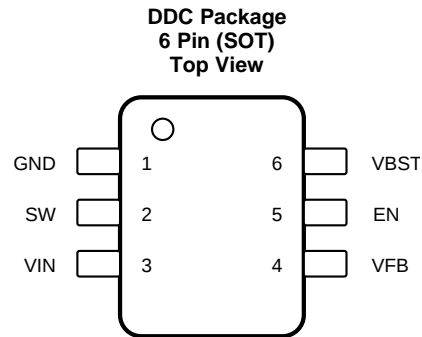
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4 修订历史记录

Changes from Original (September 2014) to Revision A		Page
•	Updated the Pinout image in Pin Configuration and Functions	3
•	Changed the "Handling Ratings" table to the ESD Ratings table	4
•	Changed $R_{\theta JB}$ for TPS562209 From: 57.3 To: 13.4 in Thermal Information	4
•	The Adaptive On-Time Control and PWM Operation , changed text From: "proportional to the converter input voltage, V_{IN} , and inversely proportional to the output voltage, V_O " To: "inversely proportional to the converter input voltage, V_{IN} , and proportional to the output voltage, V_O "	11

5 Pin Configuration and Functions



Pin Functions

PIN		DESCRIPTION
NAME	NO.	
GND	1	Ground pin Source terminal of low-side power NFET as well as the ground terminal for controller circuit. Connect sensitive VFB to this GND at a single point.
SW	2	Switch node connection between high-side NFET and low-side NFET.
VIN	3	Input voltage supply pin. The drain terminal of high-side power NFET.
VFB	4	Converter feedback input. Connect to output voltage with feedback resistor divider.
EN	5	Enable input control. Active high and must be pulled up to enable the device.
VBST	6	Supply input for the high-side NFET gate drive circuit. Connect 0.1 μ F capacitor between VBST and SW pins.

6 Specifications

6.1 Absolute Maximum Ratings

 $T_J = -40^{\circ}\text{C}$ to 150°C (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
Input voltage range	VIN, EN	-0.3	19	V
	VBST	-0.3	25	V
	VBST (10 ns transient)	-0.3	27.5	V
	VBST (vs SW)	-0.3	6.5	V
	VFB,	-0.3	6.5	V
	SW	-2	19	V
	SW (10 ns transient)	-3.5	21	V
Operating junction temperature, T_J		-40	150	$^{\circ}\text{C}$
Storage temperature, T_{stg}		-55	150	$^{\circ}\text{C}$

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			MIN	MAX	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾		2	kV
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾		500	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
 (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

 $T_J = -40^{\circ}\text{C}$ to 150°C (unless otherwise noted)

		MIN	MAX	UNIT	
V_{IN}	Supply input voltage range	4.5	17	V	
V_I	Input voltage range	VBST	-0.1	23	V
		VBST (10 ns transient)	-0.1	26	
		VBST(vs SW)	-0.1	6.0	
		EN	-0.1	17	
		VFB	-0.1	5.5	
		SW	-1.8	17	
		SW (10 ns transient)	-3.5	20	
T_A	Operating free-air temperature	-40	85	$^{\circ}\text{C}$	

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TPS562209	TPS563209	UNIT
		DDC (6 PINS)		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	109.2	87.9	$^{\circ}\text{C}/\text{W}$
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	44.5	42.2	
$R_{\theta JB}$	Junction-to-board thermal resistance	13.4	13.6	
Ψ_{JT}	Junction-to-top characterization parameter	2.3	1.9	
Ψ_{JB}	Junction-to-board characterization parameter	60.4	13.3	

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

6.5 Electrical Characteristics

 $T_J = -40^{\circ}\text{C}$ to 150°C , $V_{IN} = 12\text{V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY CURRENT						
I_{VIN}	Operating – non-switching supply current	V_{IN} current, $T_A = 25^{\circ}\text{C}$, $EN = 5\text{V}$, $V_{FB} = 0.8\text{V}$		650	900	μA
						μA
I_{VINSN}	Shutdown supply current	V_{IN} current, $T_A = 25^{\circ}\text{C}$, $EN = 0\text{V}$		3.0	10	μA
LOGIC THRESHOLD						
V_{ENH}	EN high-level input voltage	EN	1.6			V
V_{ENL}	EN low-level input voltage	EN			0.6	V
R_{EN}	EN pin resistance to GND	$V_{EN} = 12\text{V}$	225	450	900	$\text{k}\Omega$
V_{FB} VOLTAGE AND DISCHARGE RESISTANCE						
V_{FBTH}	V_{FB} threshold voltage	$T_A = 25^{\circ}\text{C}$, $V_O = 1.05\text{V}$, continuous mode operation	758	765	772	mV
I_{VFB}	V_{FB} input current	$V_{FB} = 0.8\text{V}$, $T_A = 25^{\circ}\text{C}$		0	± 0.1	mA
MOSFET						
$R_{DS(on)h}$	High side switch resistance	$T_A = 25^{\circ}\text{C}$, $V_{BST} - SW = 5.5\text{V}$ (TPS562209)		122		$\text{m}\Omega$
		$T_A = 25^{\circ}\text{C}$, $V_{BST} - SW = 5.5\text{V}$ (TPS563209)		68		
$R_{DS(on)l}$	Low side switch resistance	$T_A = 25^{\circ}\text{C}$ (TPS562209)		72		$\text{m}\Omega$
		$T_A = 25^{\circ}\text{C}$ (TPS563209)		39		
CURRENT LIMIT						
I_{ocL}	Current limit ⁽¹⁾	DC current, $V_{OUT} = 1.05\text{V}$, $L_1 = 2.2\ \mu\text{H}$	2.5	3.2	4.3	A
		DC current, $V_{OUT} = 1.05\text{V}$, $L_1 = 1.5\ \mu\text{H}$	3.5	4.2	5.3	
THERMAL SHUTDOWN						
T_{SDN}	Thermal shutdown threshold ⁽¹⁾	Shutdown temperature		155		$^{\circ}\text{C}$
		Hysteresis		35		
ON-TIME TIMER CONTROL						
t_{ON}	On time	$V_{IN} = 12\text{V}$, $V_O = 1.05\text{V}$		150		ns
$t_{OFF(MIN)}$	Minimum off time	$T_A = 25^{\circ}\text{C}$, $V_{FB} = 0.5\text{V}$		260	310	ns
SOFT START						
T_{SS}	Soft –start time	Internal soft-start time, $T_A = 25^{\circ}\text{C}$	0.7	1.0	1.3	ms
OUTPUT UNDERVOLTAGE AND OVERVOLTAGE PROTECTION						
V_{OVP}	Output OVP threshold	OVP Detect		125% \times V_{fbth}		
V_{UVP}	Output UVP threshold	Hiccup detect		65% \times V_{fbth}		
$T_{HiccupOn}$	Hiccup Power On Time	Relative to soft start time		1		ms
$T_{HiccupOff}$	Hiccup Power Off Time	Relative to soft start time		7		ms
UVLO						
UVLO	UVLO threshold	Wake up V_{IN} voltage	3.45	3.75	4.05	V
		Hysteresis V_{IN} voltage	0.13	0.32	0.55	

(1) Not production tested.

6.6 Typical Characteristics TPS562209

$V_{IN} = 12V$ (unless otherwise noted)

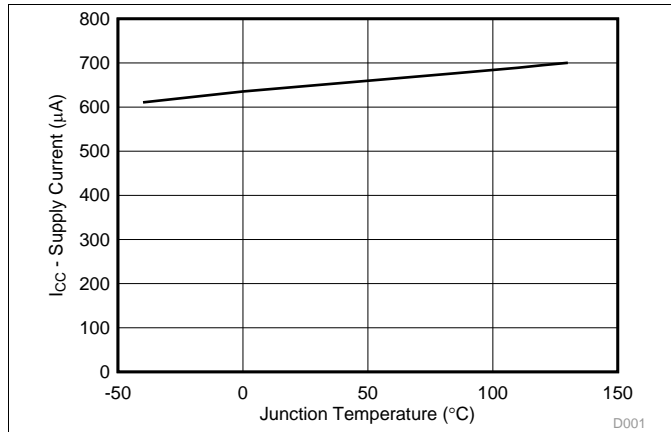


Figure 1. Supply Current vs Junction Temperature

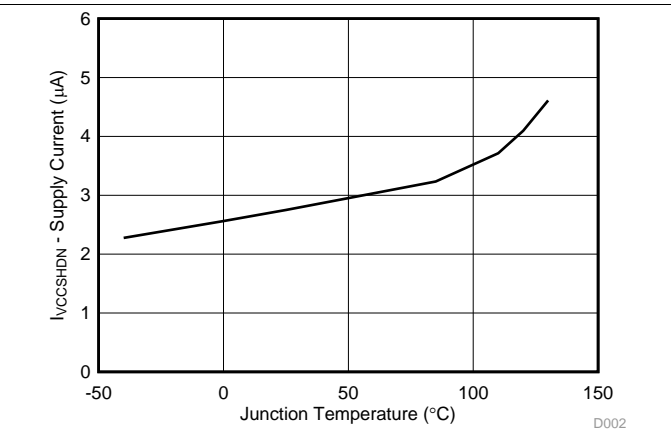


Figure 2. VIN Shutdown Current vs Junction Temperature

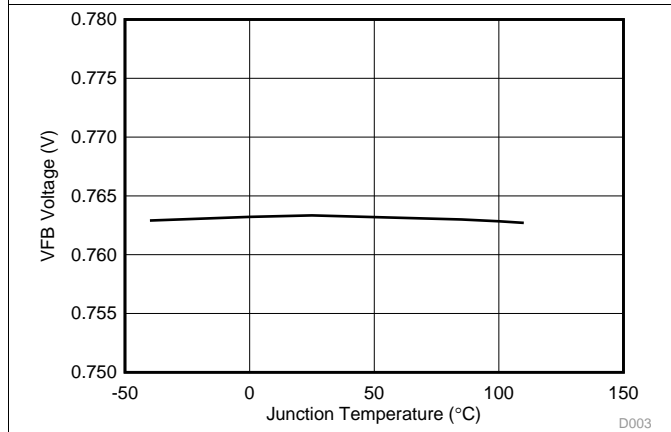


Figure 3. VFB Voltage vs Junction Temperature

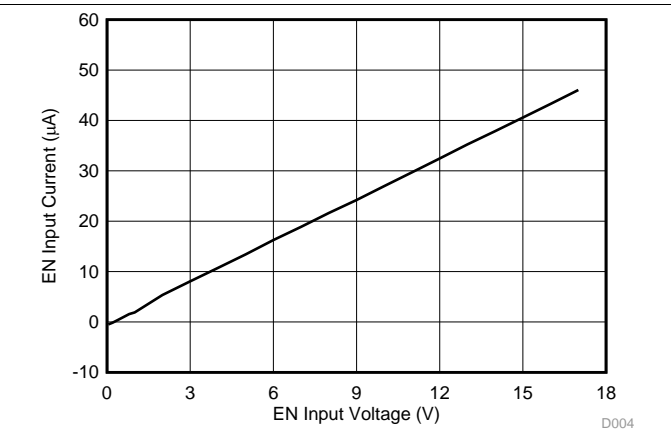


Figure 4. EN Current vs EN Voltage

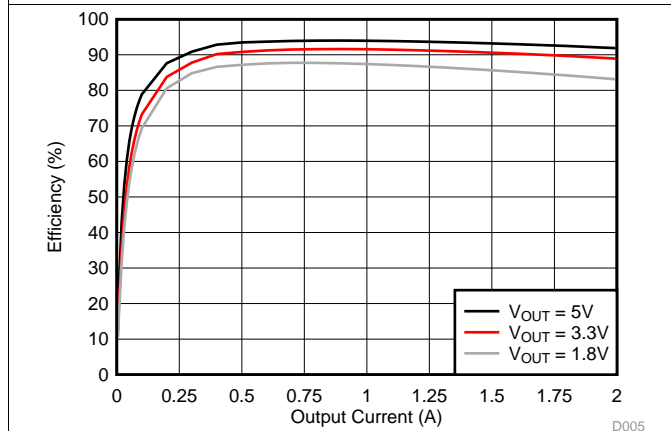


Figure 5. Efficiency vs Output Current

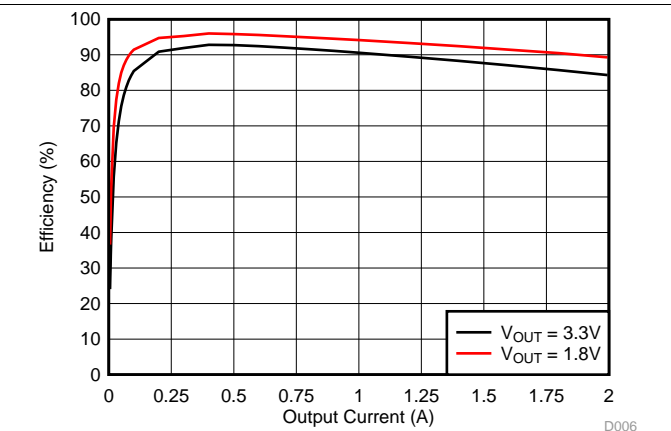


Figure 6. Efficiency vs Output current ($V_I = 5 V$)

Typical Characteristics TPS562209 (continued)

$V_{IN} = 12V$ (unless otherwise noted)

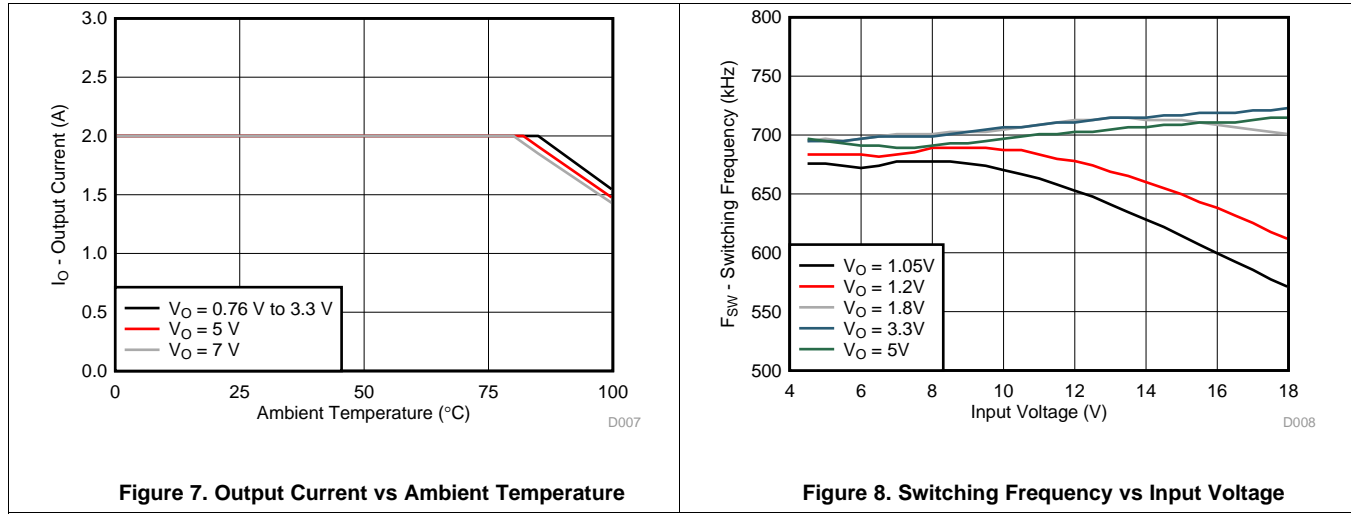


Figure 7. Output Current vs Ambient Temperature

Figure 8. Switching Frequency vs Input Voltage

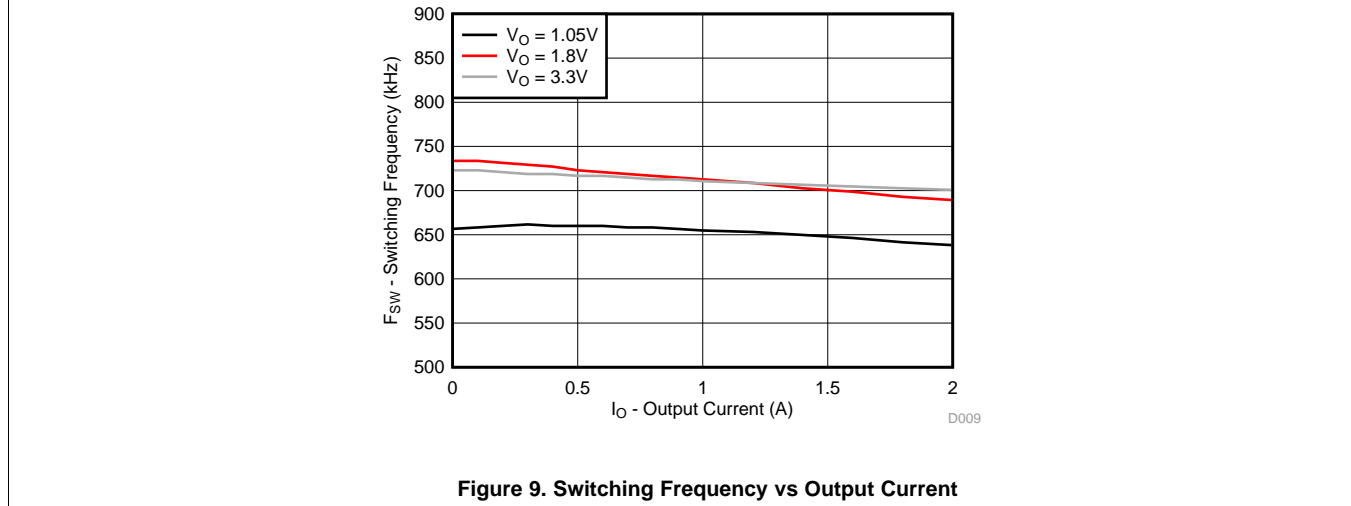


Figure 9. Switching Frequency vs Output Current

6.7 Typical Characteristics TPS563209

$V_{IN} = 12V$ (unless otherwise noted)

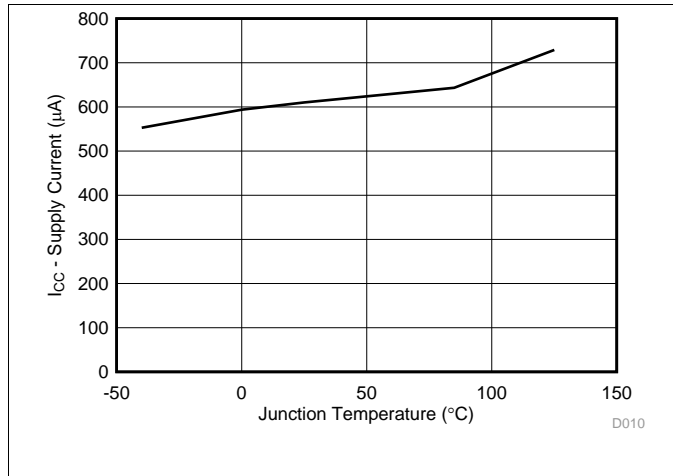


Figure 10. Supply Current vs Junction Temperature

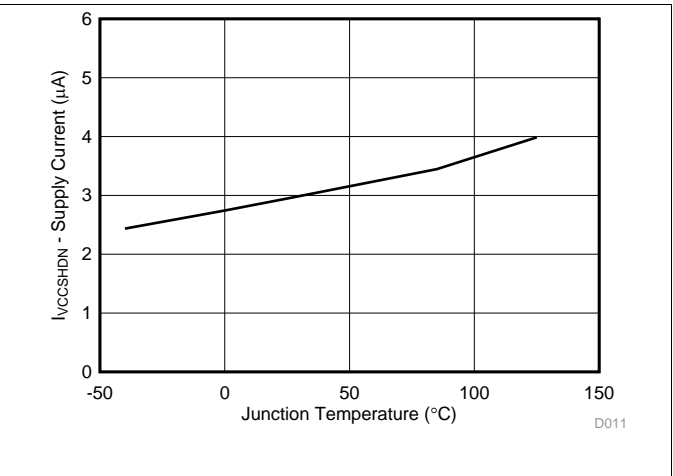


Figure 11. VIN Shutdown Current vs Junction Temperature

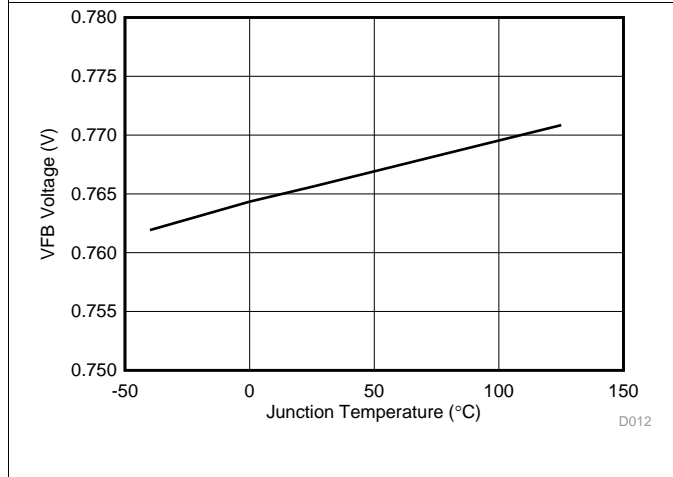


Figure 12. VFB Voltage vs Junction Temperature

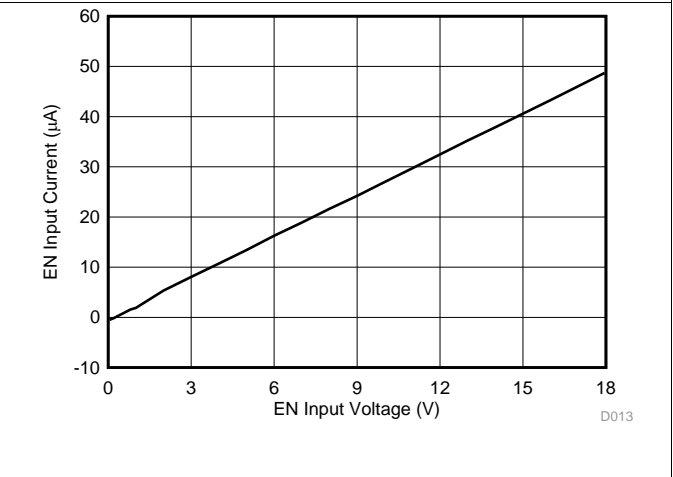


Figure 13. EN Current vs EN Voltage

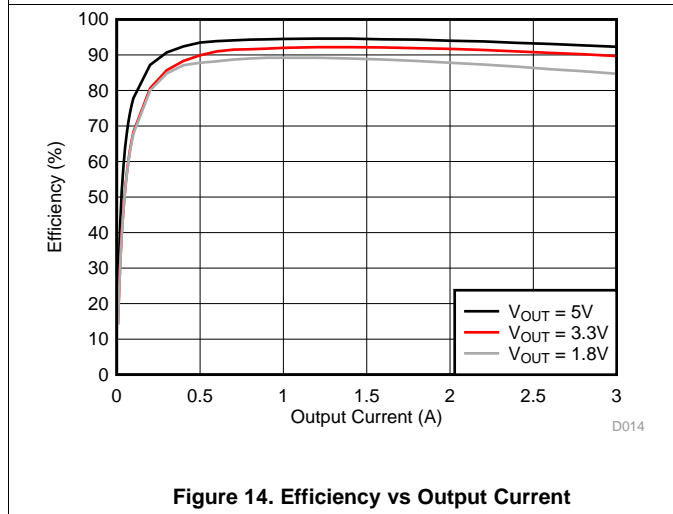


Figure 14. Efficiency vs Output Current

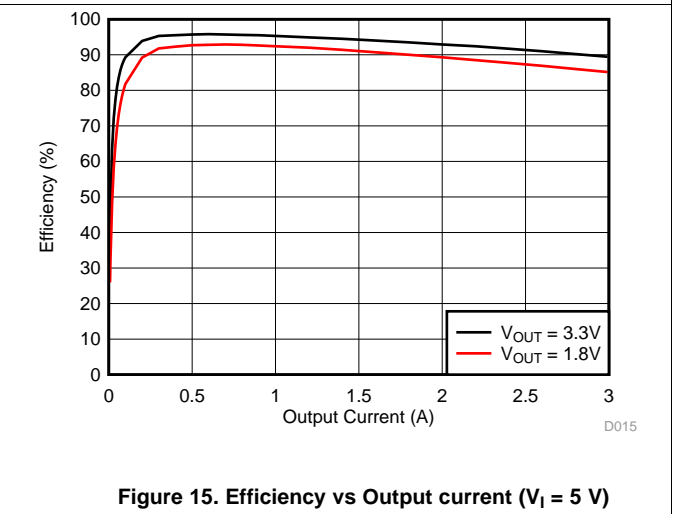
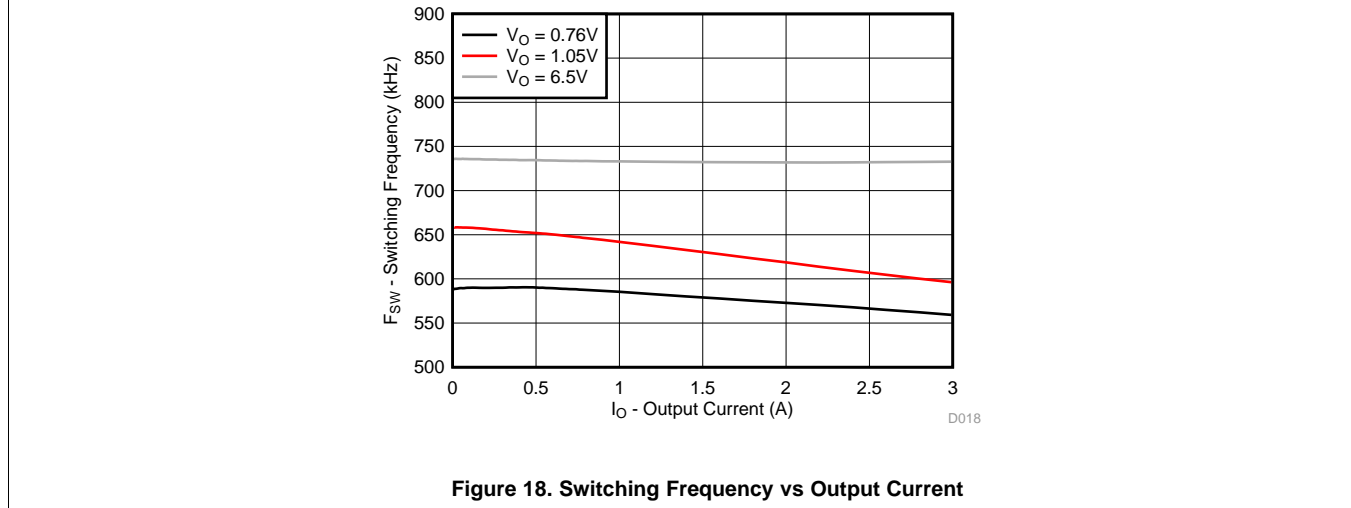
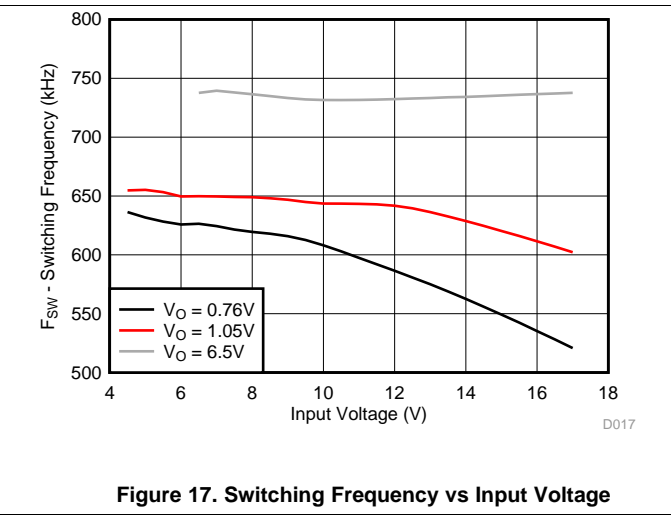
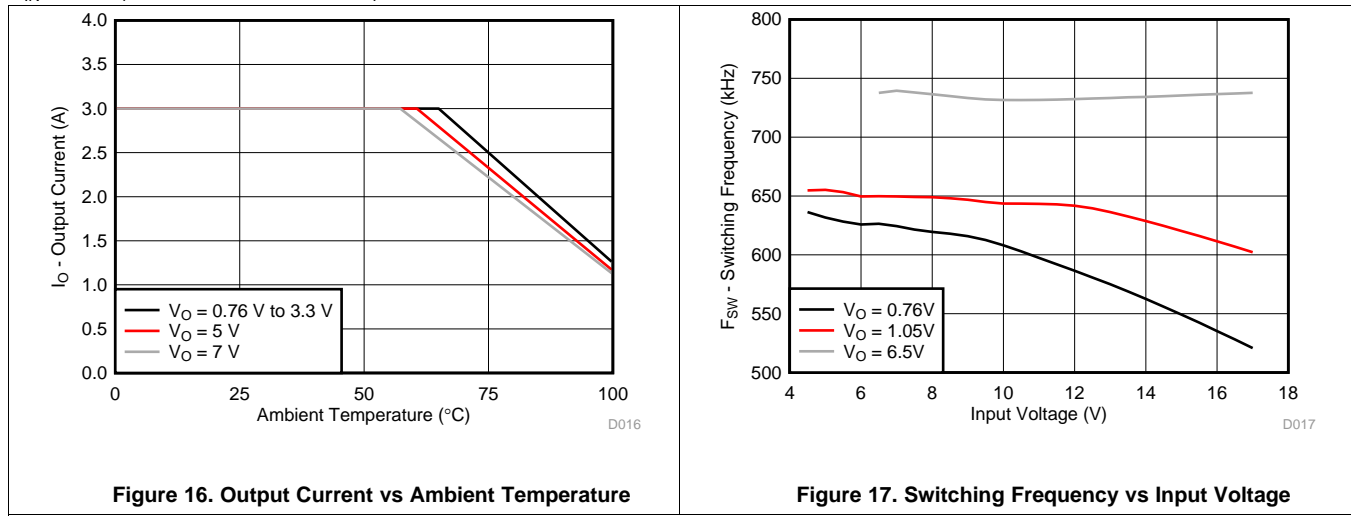


Figure 15. Efficiency vs Output current (V_I = 5 V)

Typical Characteristics TPS563209 (continued)

$V_{IN} = 12V$ (unless otherwise noted)

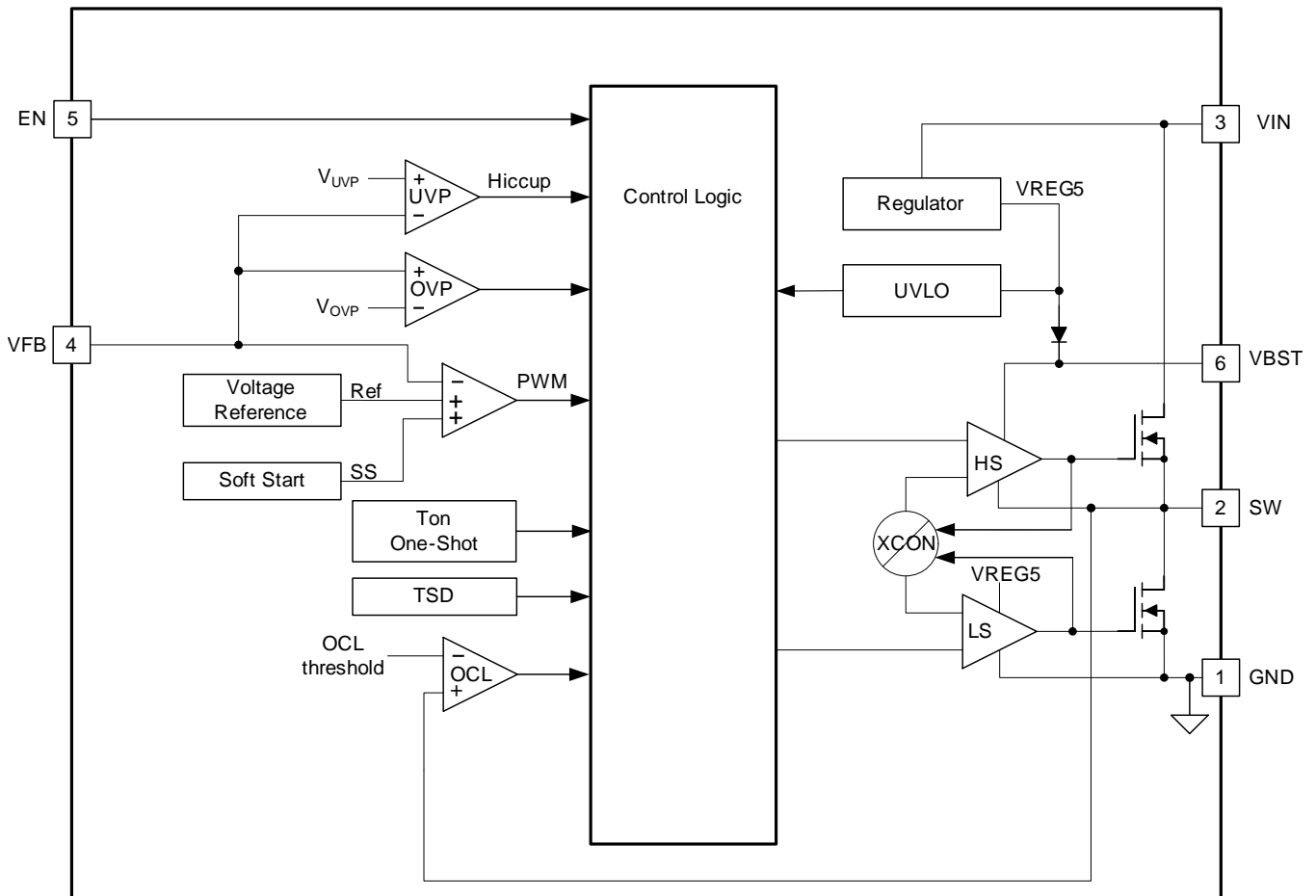


7 Detailed Description

7.1 Overview

The TPS562209 and TPS563209 are 2-A and 3-A synchronous step-down converters, respectively. The proprietary D-CAP2™ mode control supports low ESR output capacitors such as specialty polymer capacitors and multi-layer ceramic capacitors without complex external compensation circuits. The fast transient response of D-CAP2™ mode control can reduce the output capacitance required to meet a specific level of performance.

7.2 Functional Block Diagram



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Figure 19. TPS56x209

7.3 Feature Description

7.3.1 The Adaptive On-Time Control and PWM Operation

The main control loop of the TPS56x209 are adaptive on-time pulse width modulation (PWM) controller that supports a proprietary D-CAP2™ mode control. The D-CAP2™ mode control combines adaptive on-time control with an internal compensation circuit for pseudo-fixed frequency and low external component count configuration with both low ESR and ceramic output capacitors. It is stable even with virtually no ripple at the output.

At the beginning of each cycle, the high-side MOSFET is turned on. This MOSFET is turned off after internal one shot timer expires. This one shot duration is set inversely proportional to the converter input voltage, V_{IN} , and proportional to the output voltage, V_O , to maintain a pseudo-fixed frequency over the input voltage range, hence it is called adaptive on-time control. The one-shot timer is reset and the high-side MOSFET is turned on again when the feedback voltage falls below the reference voltage. An internal ramp is added to reference voltage to simulate output ripple, eliminating the need for ESR induced output ripple from D-CAP2™ mode control.

7.3.2 Soft Start and Pre-Biased Soft Start

The TPS562209 and TPS563209 have an internal 1.0ms soft-start. When the EN pin becomes high, the internal soft-start function begins ramping up the reference voltage to the PWM comparator.

If the output capacitor is pre-biased at startup, the devices initiate switching and start ramping up only after the internal reference voltage becomes greater than the feedback voltage V_{FB} . This scheme ensures that the converters ramp up smoothly into regulation point.

7.3.3 Current Protection

The output over-current limit (OCL) is implemented using a cycle-by-cycle valley detect control circuit. The switch current is monitored during the OFF state by measuring the low-side FET drain to source voltage. This voltage is proportional to the switch current. To improve accuracy, the voltage sensing is temperature compensated. During the on time of the high-side FET switch, the switch current increases at a linear rate determined by V_{in} , V_{out} , the on-time and the output inductor value.

During the on time of the low-side FET switch, this current decreases linearly. The average value of the switch current is the load current I_{out} . If the monitored current is above the OCL level, the converter maintains low-side FET on and delays the creation of a new set pulse, even the voltage feedback loop requires one, until the current level becomes OCL level or lower. In subsequent switching cycles, the on-time is set to a fixed value and the current is monitored in the same manner. If the over current condition exists consecutive switching cycles, the internal OCL threshold is set to a lower level, reducing the available output current. When a switching cycle occurs where the switch current is not above the lower OCL threshold, the counter is reset and the OCL threshold is returned to the higher value.

There are some important considerations for this type of over-current protection. The load current is higher than the over-current threshold by one half of the peak-to-peak inductor ripple current. Also, when the current is being limited, the output voltage tends to fall as the demanded load current may be higher than the current available from the converter. This may cause the output voltage to fall. When the VFB voltage falls below the UVP threshold voltage, the UVP comparator detects it. And then, the device will shut down after the UVP delay time (typically 14 μ s) and re-start after the hiccup time (typically 12ms).

When the over current condition is removed, the output voltage returns to the regulated value.

7.3.4 Over Voltage Protection

TPS562209 and TPS563209 detect over voltage condition by monitoring the feedback voltage (VFB). When the feedback voltage becomes higher than 125% of the target voltage, the OVP comparator output goes high and both the high-side MOSFET and the low-side MOSFET turn off. This function is non-latch operation.

7.3.5 UVLO Protection

Under voltage lock out protection (UVLO) monitors the device input voltage. When the voltage is lower than UVLO threshold voltage, the device is shut off. This protection is non-latching.

Feature Description (continued)

7.3.6 Thermal Shutdown

The device monitors the temperature of itself. If the temperature exceeds the threshold value (typically 155°C), the device is shut off. This is a non-latch protection.

7.4 Device Functional Modes

7.4.1 Normal Operation

When the input voltage is above the UVLO threshold and the EN voltage is above the enable threshold, the TPS562209 and TPS563209 can operate in their normal switching modes. Normal continuous conduction mode (CCM) occurs when the minimum switch current is above 0 A. In CCM, the TPS562209 and TPS563209 operate at a quasi-fixed frequency of 650 kHz.

7.4.2 Forced CCM Operation

When the TPS562209 and TPS563209 are in the normal CCM operating mode and the switch current falls below 0 A, the TPS562209 and TPS563209 begin operating in forced CCM.

7.4.3 Standby Operation

When the TPS562209 and TPS563209 are operating in either normal CCM or forced CCM, they may be placed in standby by asserting the EN pin low.

8 Application and Implementation

NOTE

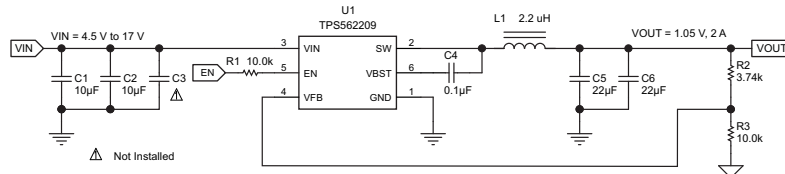
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TPS562209 and TPS563209 are typically used as step down converters, which convert a voltage from 4.5V - 17V to a lower voltage. Webench software is available to aid in the design and analysis of circuits

8.2 Typical Applications

8.2.1 TPS562209 4.5-V to 17-V Input, 1.05-V Output Converter



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Figure 20. TPS562209 1.05V/2A Reference Design

8.2.1.1 Design Requirements

To begin the design process, you must know a few application parameters:

Table 1. Design Parameters

PARAMETER	VALUE
Input voltage range	4.5 V to 17 V
Output voltage	1.05 V
Output current	2 A
Output voltage ripple	20 mVpp

8.2.1.2 Detailed Design Procedure

8.2.1.2.1 Output Voltage Resistors Selection

The output voltage is set with a resistor divider from the output node to the VFB pin. It is recommended to use 1% tolerance or better divider resistors. Start by using Equation 1 to calculate V_{OUT} .

To improve efficiency at very light loads consider using larger value resistors, too high of resistance will be more susceptible to noise and voltage errors from the VFB input current will be more noticeable.

$$V_{OUT} = 0.765 \times \left(1 + \frac{R2}{R3} \right) \quad (1)$$

8.2.1.2.2 Output Filter Selection

The LC filter used as the output filter has double pole at:

$$F_P = \frac{1}{2\pi\sqrt{L_{OUT} \times C_{OUT}}} \quad (2)$$

At low frequencies, the overall loop gain is set by the output set-point resistor divider network and the internal gain of the device. The low frequency phase is 180 degrees. At the output filter pole frequency, the gain rolls off at a –40 dB per decade rate and the phase drops rapidly. D-CAP2™ introduces a high frequency zero that reduces the gain roll off to –20 dB per decade and increases the phase to 90 degrees one decade above the zero frequency. The inductor and capacitor for the output filter must be selected so that the double pole of Equation 2 is located below the high frequency zero but close enough that the phase boost provided by the high frequency zero provides adequate phase margin for a stable circuit. To meet this requirement use the values recommended in Table 2.

Table 2. Recommended Component Values

OUTPUT VOLTAGE (V)	R2 (kΩ)	R3 (kΩ)	L1 (μH)			C5 + C6 (μF)
			MIN	TYP	MAX	
1	3.09	10.0	1.5	2.2	4.7	20 - 68
1.05	3.74	10.0	1.5	2.2	4.7	20 - 68
1.2	5.76	10.0	1.5	2.2	4.7	20 - 68
1.5	9.53	10.0	1.5	2.2	4.7	20 - 68
1.8	13.7	10.0	1.5	2.2	4.7	20 - 68
2.5	22.6	10.0	2.2	3.3	4.7	20 - 68
3.3	33.2	10.0	2.2	3.3	4.7	20 - 68
5	54.9	10.0	3.3	4.7	4.7	20 - 68
6.5	75	10.0	3.3	4.7	4.7	20 - 68

The inductor peak-to-peak ripple current, peak current and RMS current are calculated using Equation 3, Equation 4 and Equation 5. The inductor saturation current rating must be greater than the calculated peak current and the RMS or heating current rating must be greater than the calculated RMS current.

Use 650 kHz for f_{SW} . Make sure the chosen inductor is rated for the peak current of Equation 4 and the RMS current of Equation 5.

$$I_{P-P} = \frac{V_{OUT}}{V_{IN(MAX)}} \times \frac{V_{IN(MAX)} - V_{OUT}}{L_O \times f_{SW}} \quad (3)$$

$$I_{PEAK} = I_O + \frac{I_{P-P}}{2} \quad (4)$$

$$I_{LO(RMS)} = \sqrt{I_O^2 + \frac{1}{12} I_{P-P}^2} \quad (5)$$

For this design example, the calculated peak current is 2.34 A and the calculated RMS current is 2.01 A. The inductor used is a TDK CLF7045T-2R2N with a peak current rating of 5.5-A and an RMS current rating of 4.3-A

The capacitor value and ESR determines the amount of output voltage ripple. The TPS562209 is intended for use with ceramic or other low ESR capacitors. Recommended values range from 20μF to 68μF. Use Equation 6 to determine the required RMS current rating for the output capacitor.

$$I_{CO(RMS)} = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{\sqrt{12} \times V_{IN} \times L_O \times f_{SW}} \quad (6)$$

For this design two TDK C3216X5R0J226M 22μF output capacitors are used. The typical ESR is 2 mΩ each. The calculated RMS current is 0.199A and each output capacitor is rated for 4A.

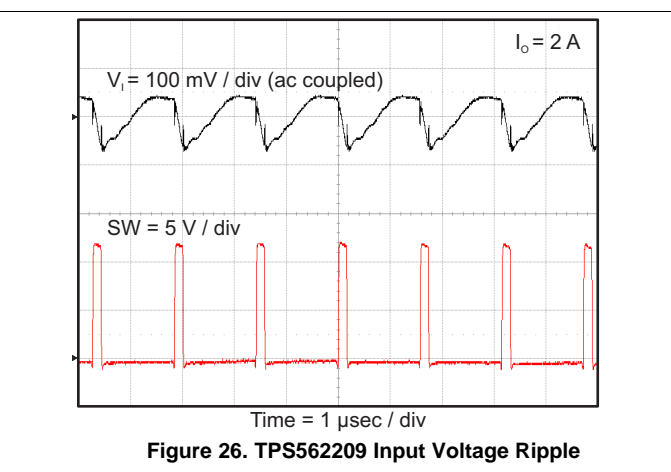
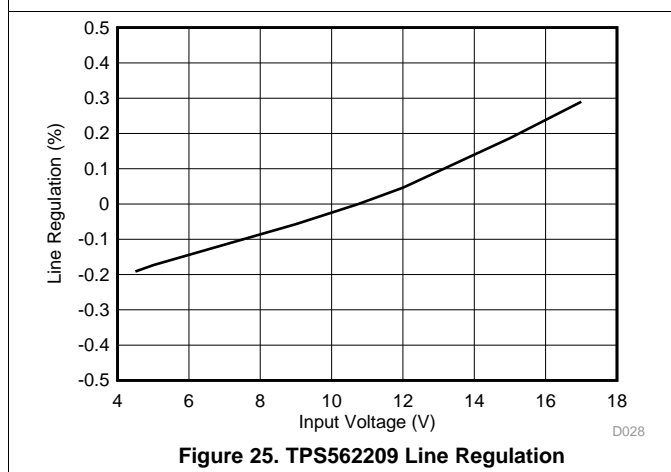
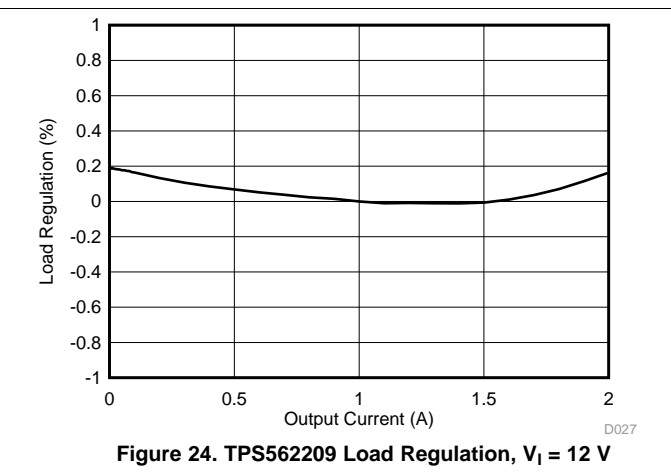
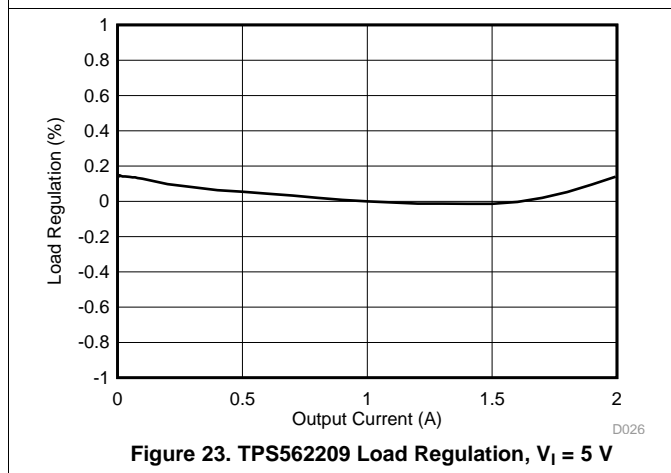
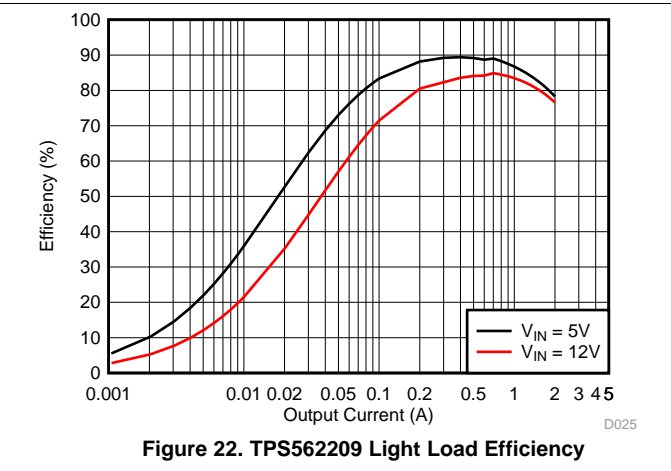
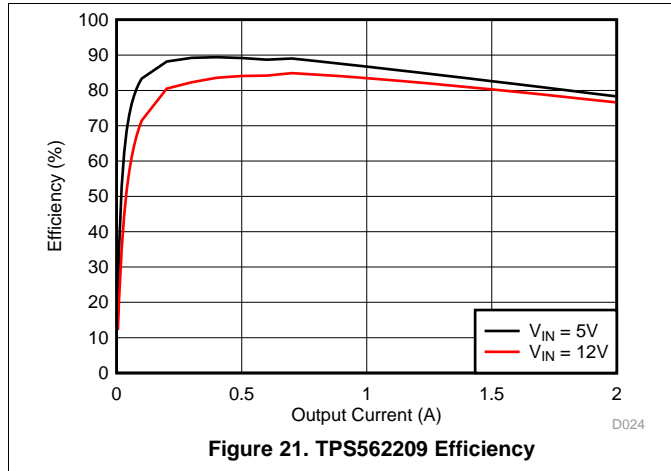
8.2.1.2.3 Input Capacitor Selection

The TPS562209 and TPS563209 require an input decoupling capacitor and a bulk capacitor is needed depending on the application. A ceramic capacitor over 10 μF is recommended for the decoupling capacitor. An additional 0.1 μF capacitor (C3) from pin 3 to ground is optional to provide additional high frequency filtering. The capacitor voltage rating needs to be greater than the maximum input voltage.

8.2.1.2.4 Bootstrap Capacitor Selection

A 0.1µF ceramic capacitor must be connected between the VBST to SW pin for proper operation. It is recommended to use a ceramic capacitor.

8.2.1.3 Application Curves



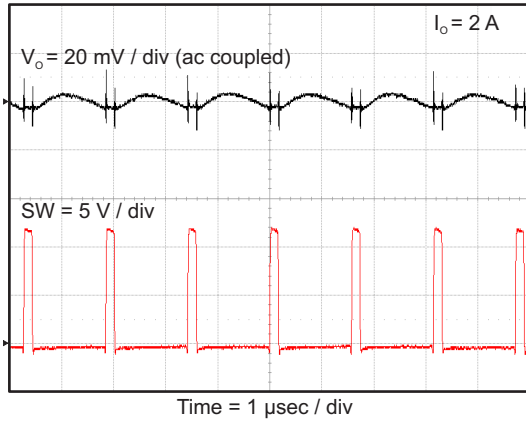


Figure 27. TPS562209 Output Voltage Ripple

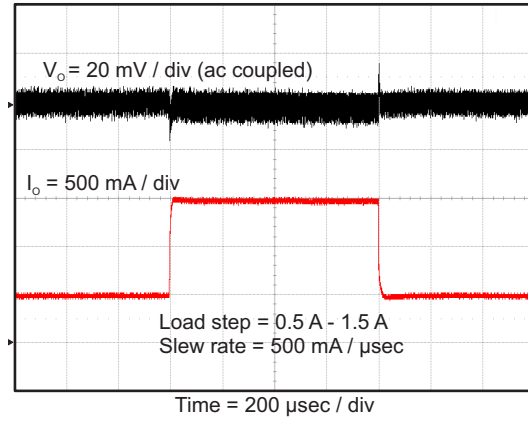


Figure 28. TPS562209 Transient Response

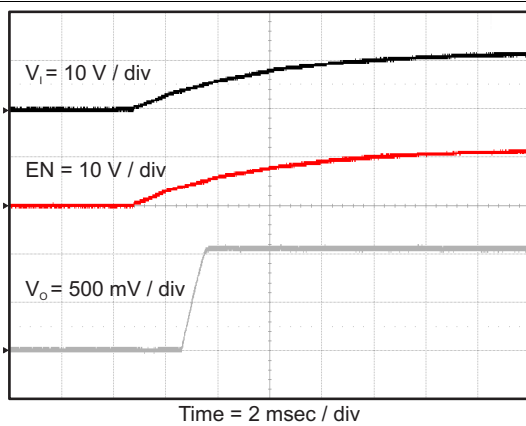


Figure 29. TPS562209 Start Up Relative to V_I

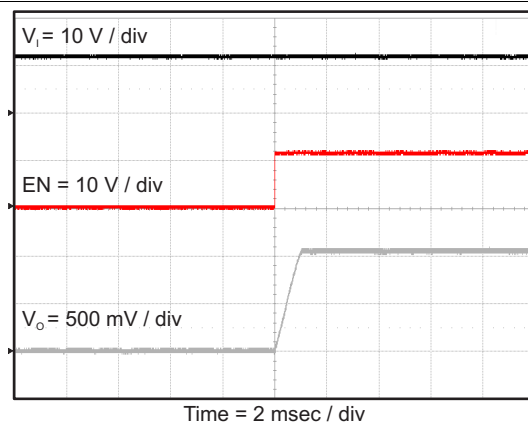


Figure 30. TPS562209 Start Up Relative to EN

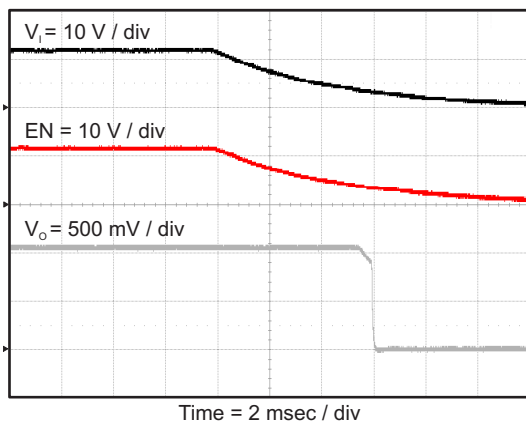


Figure 31. TPS562209 Shut Down Relative to V_I

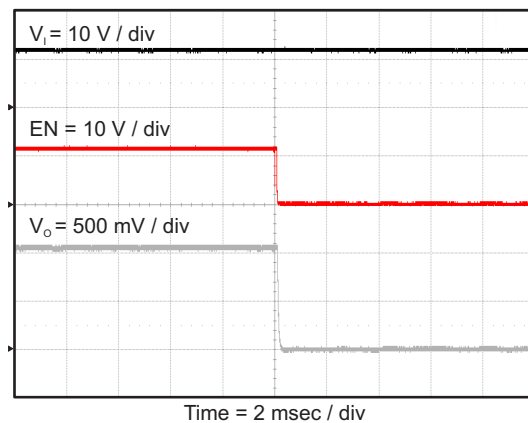
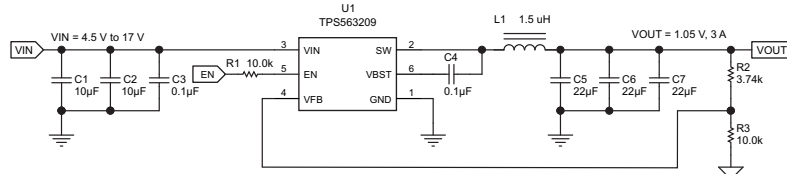


Figure 32. TPS562209 Shut Down Relative to EN

8.2.2 TPS563209 4.5-V to 17-V Input, 1.05-V Output Converter



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Figure 33. TPS563209 1.05V/3A Reference Design

8.2.2.1 Design Requirements

To begin the design process, the user must know a few application parameters:

Table 3. Design Parameters

PARAMETER	VALUE
Input voltage range	4.5 V to 17 V
Output voltage	1.05 V
Output current	3 A
Output voltage ripple	20 mVpp

8.2.2.2 Detailed Design Procedures

The detailed design procedure for TPS563209 is the same as for TPS562209 except for inductor selection.

8.2.2.2.1 Output Filter Selection

Table 4. Recommended Component Values

OUTPUT VOLTAGE (V)	R2 (kΩ)	R3 (kΩ)	L1 (µH)			C5 +C6 + C7 (µF)
			MIN	TYP	MAX	
1	3.09	10.0	1.0	1.5	4.7	20 - 68
1.05	3.74	10.0	1.0	1.5	4.7	20 - 68
1.2	5.76	10.0	1.0	1.5	4.7	20 - 68
1.5	9.53	10.0	1.0	1.5	4.7	20 - 68
1.8	13.7	10.0	1.5	2.2	4.7	20 - 68
2.5	22.6	10.0	1.5	2.2	4.7	20 - 68
3.3	33.2	10.0	1.5	2.2	4.7	20 - 68
5	54.9	10.0	2.2	3.3	4.7	20 - 68
6.5	75	10.0	2.2	3.3	4.7	20 - 68

The inductor peak-to-peak ripple current, peak current and RMS current are calculated using Equation 7, Equation 8 and Equation 9. The inductor saturation current rating must be greater than the calculated peak current and the RMS or heating current rating must be greater than the calculated RMS current. Use 650 kHz for f_{sw} .

Use 650 kHz for f_{sw} . Make sure the chosen inductor is rated for the peak current of Equation 8 and the RMS current of Equation 9.

$$I_{P-P} = \frac{V_{OUT}}{V_{IN(MAX)}} \times \frac{V_{IN(MAX)} - V_{OUT}}{L_O \times f_{SW}} \quad (7)$$

$$I_{PEAK} = I_O + \frac{I_{P-P}}{2} \quad (8)$$

$$I_{LO(RMS)} = \sqrt{I_O^2 + \frac{1}{12} I_{P-P}^2} \tag{9}$$

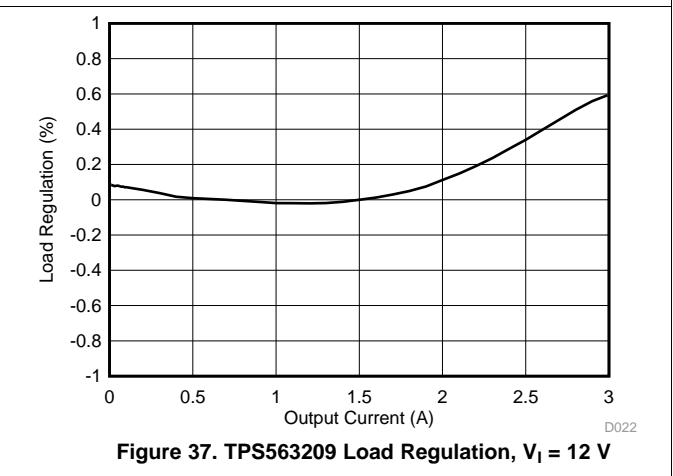
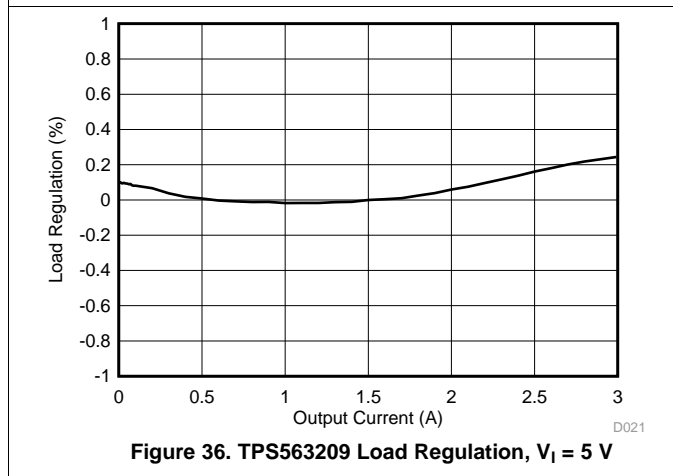
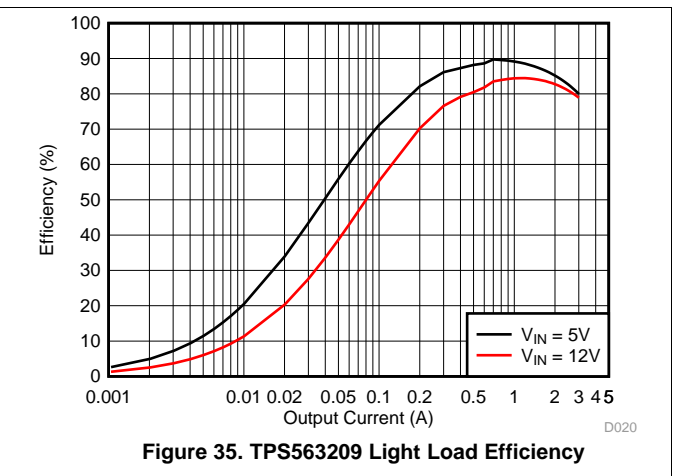
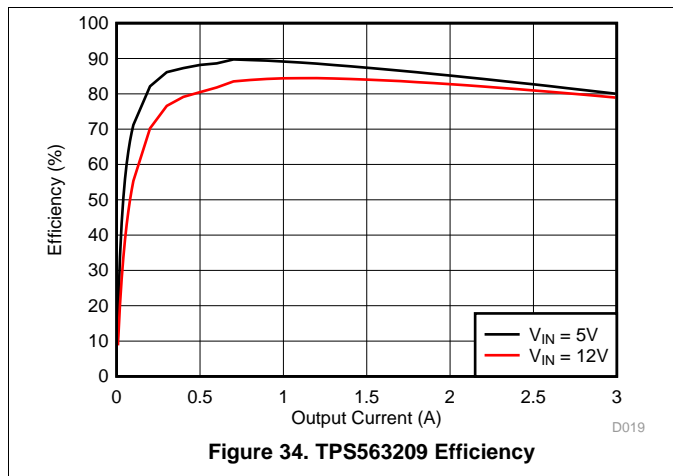
For this design example, the calculated peak current is 3.505 A and the calculated RMS current is 3.014 A. The inductor used is a TDK CLF7045T-1R5N with a peak current rating of 7.3-A and an RMS current rating of 4.9-A

The capacitor value and ESR determines the amount of output voltage ripple. The TPS563209 is intended for use with ceramic or other low ESR capacitors. Recommended values range from 20µF to 68µF. Use Equation 6 to determine the required RMS current rating for the output capacitor.

$$I_{CO(RMS)} = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{\sqrt{12} \times V_{IN} \times L_O \times f_{SW}} \tag{10}$$

For this design three TDK C3216X5R0J226M 22µF output capacitors are used. The typical ESR is 2 mΩ each. The calculated RMS current is 0.292A and each output capacitor is rated for 4A.

8.2.2.3 Application Curves



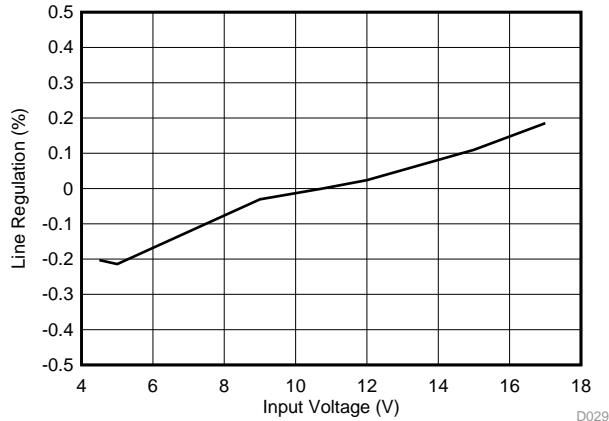


Figure 38. TPS563209 Line Regulation

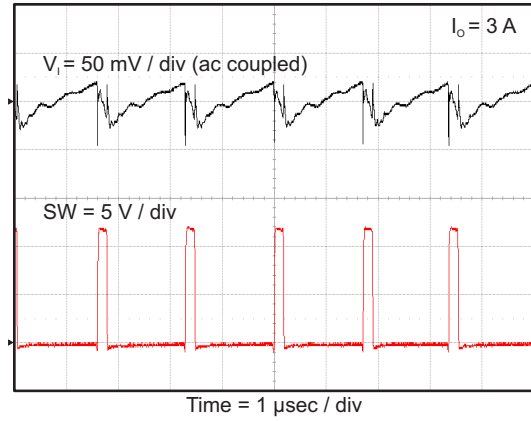


Figure 39. TPS563209 Input Voltage Ripple

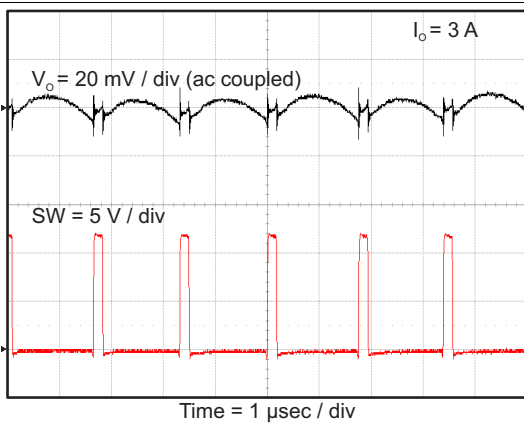


Figure 40. TPS563209 Output Voltage Ripple

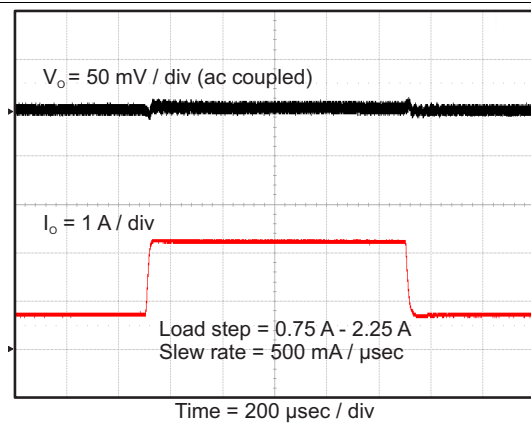


Figure 41. TPS563209 Transient Response

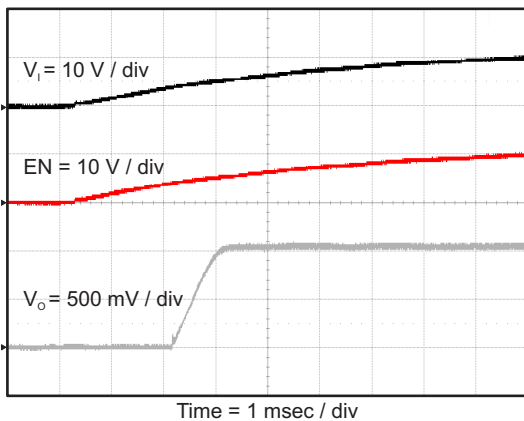


Figure 42. TPS563209 Start Up Relative to V₁

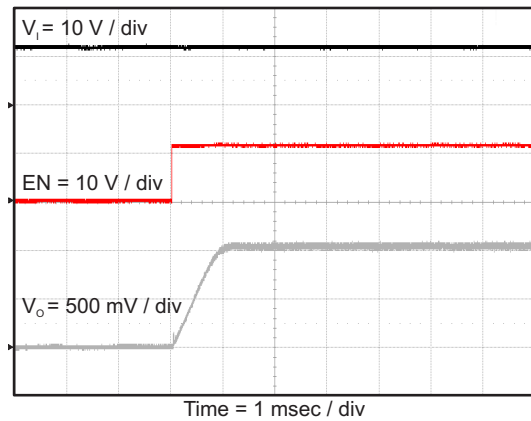
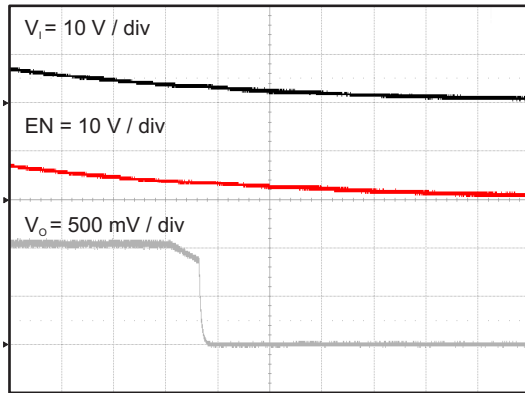
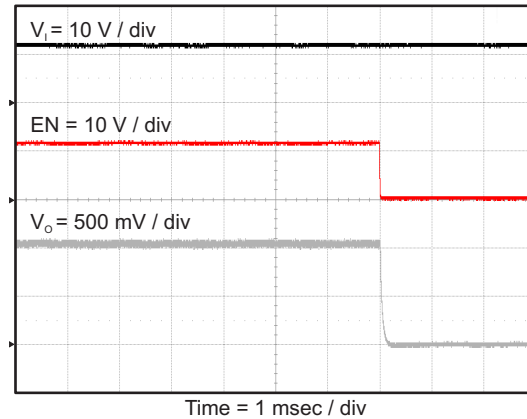


Figure 43. TPS563209 Start Up Relative to EN


Figure 44. TPS563209 Shut Down Relative to V_I

Figure 45. TPS563209 Shut Down Relative to EN

9 Power Supply Recommendations

The TPS562209 and TPS563209 are designed to operate from input supply voltage in the range of 4.5V to 17V. Buck converters require the input voltage to be higher than the output voltage for proper operation. The maximum recommended operating duty cycle is 65%. Using that criteria, the minimum recommended input voltage is $V_O / 0.65$.

10 Layout

10.1 Layout Guidelines

1. VIN and GND traces should be as wide as possible to reduce trace impedance. The wide areas are also of advantage from the view point of heat dissipation.
2. The input capacitor and output capacitor should be placed as close to the device as possible to minimize trace impedance.
3. Provide sufficient vias for the input capacitor and output capacitor.
4. Keep the SW trace as physically short and wide as practical to minimize radiated emissions.
5. Do not allow switching current to flow under the device.
6. A separate VOUT path should be connected to the upper feedback resistor.
7. Make a Kelvin connection to the GND pin for the feedback path.
8. Voltage feedback loop should be placed away from the high-voltage switching trace, and preferably has ground shield.
9. The trace of the VFB node should be as small as possible to avoid noise coupling.
10. The GND trace between the output capacitor and the GND pin should be as wide as possible to minimize its trace impedance.

10.2 Layout Example

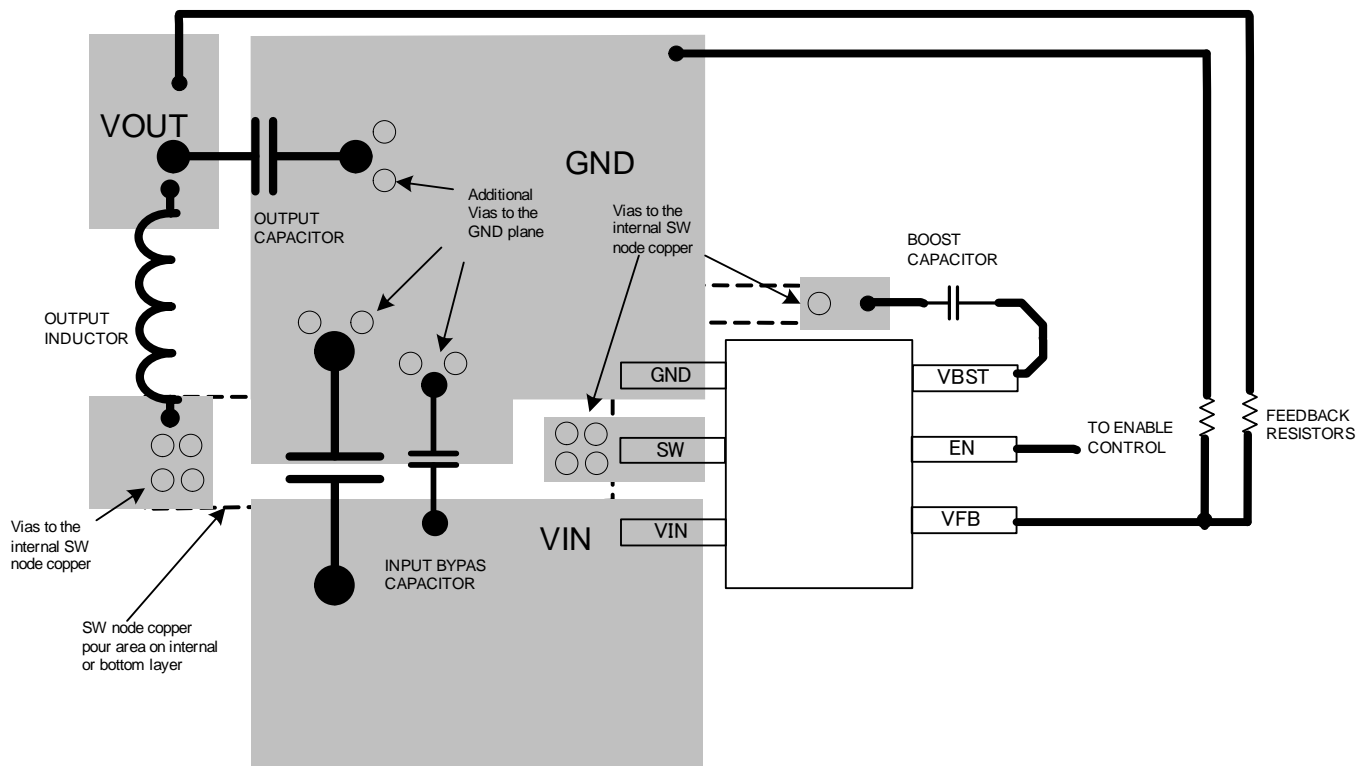


Figure 46. TPS562209 and TPS563209 Layout

11 器件和文档支持

11.1 相关链接

下面的表格列出了快速访问链接。范围包括技术文档、支持与社区资源、工具和软件，并且可以快速访问样片或购买链接。

表 5. 相关链接

器件	产品文件夹	样片与购买	技术文档	工具与软件	支持与社区
TPS563209	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处
TPS562209	请单击此处	请单击此处	请单击此处	请单击此处	请单击此处

11.2 接收文档更新通知

如需接收文档更新通知，请访问 www.ti.com.cn 网站上的器件产品文件夹。点击右上角的提醒我 (Alert me) 注册后，即可每周定期收到已更改的产品信息。有关更改的详细信息，请查阅已修订文档中包含的修订历史记录。

11.3 社区资源

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Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

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11.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 机械、封装和可订购信息

以下页中包括机械、封装和可订购信息。这些信息是针对指定器件可提供的最新数据。这些数据会在无通知且不对本文档进行修订的情况下发生改变。欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS562209DDCR	ACTIVE	SOT-23-THIN	DDC	6	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	209	Samples
TPS562209DDCT	ACTIVE	SOT-23-THIN	DDC	6	250	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	209	Samples
TPS563209DDCR	ACTIVE	SOT-23-THIN	DDC	6	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	309	Samples
TPS563209DDCT	ACTIVE	SOT-23-THIN	DDC	6	250	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	309	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS562209DDCR	SOT-23-THIN	DDC	6	3000	180.0	9.5	3.17	3.1	1.1	4.0	8.0	Q3
TPS562209DDCT	SOT-23-THIN	DDC	6	250	180.0	9.5	3.17	3.1	1.1	4.0	8.0	Q3
TPS563209DDCR	SOT-23-THIN	DDC	6	3000	180.0	9.5	3.17	3.1	1.1	4.0	8.0	Q3
TPS563209DDCT	SOT-23-THIN	DDC	6	250	180.0	9.5	3.17	3.1	1.1	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS562209DDCR	SOT-23-THIN	DDC	6	3000	184.0	184.0	19.0
TPS562209DDCT	SOT-23-THIN	DDC	6	250	184.0	184.0	19.0
TPS563209DDCR	SOT-23-THIN	DDC	6	3000	184.0	184.0	19.0
TPS563209DDCT	SOT-23-THIN	DDC	6	250	184.0	184.0	19.0

DDC (R-PDSO-G6)

PLASTIC SMALL-OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion.
 - Falls within JEDEC MO-193 variation AA (6 pin).

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邮寄地址：上海市浦东新区世纪大道 1568 号中建大厦 32 楼，邮政编码：200122
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